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Antenna on Chip (AoC) Design Using Metasurface and SIW Technologies for THz Wireless Applications

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Abstract: This paper presents the design of a high-performance 0.45–0.50 THz antenna on chip (AoC) for fabrication on a 100-micron GaAs substrate. The antenna is based on metasurface and substrate-integrated waveguide (SIW) technologies. It is constituted from seven stacked layers consisting of copper patch–silicon oxide–feedline–silicon oxide–aluminium–GaAs–copper ground. The top layer consists of a 2 × 4 array of rectangular metallic patches with a row of subwavelength circular slots to transform the array into a metasurface. This essentially enlarges the effective aperture area of the antenna. The antenna is excited using a coplanar waveguide feedline that is sandwiched between the two silicon oxide layers below the patch layer. The proposed antenna structure reduces substrate loss and surface waves. The AoC has dimensions of $0.8 \times 0.8 \times 0.13$ mm³. The results show that the proposed structure greatly enhances the antenna's gain and radiation efficiency, and this is achieved without compromising its physical size. The antenna exhibits an average gain and efficiency of 6.5 dBi and 65%, respectively, which makes it a promising candidate for emerging terahertz applications.

Keywords: Antenna on chip (AoC); metasurface; terahertz (THz); substrate integrated waveguide (SIW); gallium arsenide (GaAs)

1. Introduction

Smart wireless devices have grown in popularity at an exponential rate. This has caused an explosion of data traffic in the limited prescribed bandwidth resources [1]. It is estimated that the data rate in the next decade is going to be in the order of Tbps [2,3]. Although it has been shown that THz communication can easily provide a Gbps data rate, we are at a nascent stage of development for data rates in the Tbps [4,5]. THz waves benefit from being sandwiched between the millimeter and light waves in the electromagnetic spectrum. Compared with millimeter waves, THz waves have a wider usable frequency band and focused beam directivity that makes them highly unsusceptible to interference issues. Compared with light waves, THz waves have a stronger penetration power [6].

Antennas have a direct bearing on the performance of wireless systems in terms of operating bandwidth, radiation gain, and efficiency. These parameters have an impact on the system's data transmission rate, imaging resolution, and range. Compared with millimeter waves, the design of THz antennas is highly challenging as THz antennas operate at much higher frequencies and their size is significantly smaller. Moreover, the packaging of THz antennas is limited by materials and process technologies. Additionally,



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Copyright: © 2021 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). free-space path loss is an inevitable characteristic of all wireless communication. However, THz waves are greatly absorbed by the atmosphere. Hence, increasing the gain of the THz antenna is an important requirement to compensate for the free-space path loss. Moreover, THz antennas suffer from relatively high loss, which makes them currently impractical for on-chip fabrication.

An antenna is the first element in a wireless receiver and the last element in a transmitter. To guarantee optimum power transfer between the antenna and the RF-integrated circuitry, it is necessary to include an impedance matching network at the junction of the antenna and the RF circuitry. Typically, antennas are matched to a 50 Ohm impedance system, which normally requires converting the complex impedance of the system to 50 Ohm [7]. This is achieved by employing conjugate matching, in which the imaginary section of two impedances has an identical magnitude but reverse signs. Additionally, bond wires are used to connect the THz antenna to the integrated circuit. As bond wires are not characterized well at THz, the matching is often suboptimal [6].

On-chip realizations of antennas overcome the abovementioned limitations as impedances of integrated circuit elements do not need to be matched with 50 Ohm [8–10]. Co-design of circuits and antennas guarantee that complex impedances are conjugately matched with no need for a matching circuit, thus saving several additional elements, area, expense, and numerous design attempts. Furthermore, the antenna on chip (AoC) omits any doubt with bond-wires as metal interlinks are used to interface the integrated circuit to the antenna feed point [11].

Antennas for on-chip applications need to be planar as they need to be fabricated using the same integrated circuit processing. A low-resistivity substrate (10–20 Ω cm) is a common choice for the fabrication of CMOS circuits, which is necessity to overcome the latch-up issue. This type of substrate, however, greatly limits the efficiency of planar antennas resulting from high ohmic and dielectric loss in the underlying silicon substrate. A dipole antenna fabricated on a 10 Ω cm silicon substrate typically has a limited efficiency of 10% [12,13].

Proposed in this paper is a technique to overcome the limitations on bandwidth, gain, and efficiency of THz antennas fabricated on-chip. This is achieved by employing two different technologies, namely a substrate-integrated waveguide (SIW) and a 2D metamaterial, which is commonly referred to as a metasurface [14]. The proposed technique reduces the loss due to the substrate and suppresses the adverse effects of surface waves. The results confirm this has notable improvement in the radiation characteristics of AoC.

2. Antenna on Chip Design

The proposed AoC is constituted from several stacked layers comprising Cu–SiO₂– Cu–SiO₂–Al–GaAs–Cu as shown in Figure 1. The top layer consists of a 2×4 array of rectangular copper patches. Etched on the patches is a row of subwavelength circular slots. The antenna is excited using proximity coupling at the patch edge, which is analogous to a gap coupling patch. This is achieved with a microstrip coplanar waveguide feedline, which is created by having both sides next to the feedline grounded. The feedline is sandwiched between the two silicon oxide layers, below which is a layer with aluminium patches that are separated from each other by a narrow gap. This layer acts like a partially reflective surface. The outer periphery of the aluminium patches is studded with an arrangement of densely lined metallic posts or vias connecting it to the ground-plane through the GaAs substrate to create a SIW electromagnetic resonant cavity. Incident electromagnetic waves that penetrate through the gaps in the aluminium layer are reflected at the groundplane. The thickness of the GaAs substrate is such that the phase shift of the ground-plane reflected waves is in phase with the waves reflected at the surface of the copper patches. With this arrangement, the aluminium surface acts like an artificial magnetic conductor (AMC) that fully reflects incident waves with a near zero degrees reflection phase [15]. This configuration results in significantly enhanced directivity. The circular slots across the rectangular patches act like miniature resonators that radiate energy at the THz band.



The antenna was implemented on a GaAs substrate of 100-micron thickness, a dielectric constant of 12.94, and a loss-tangent of 0.006.

Figure 1. The proposed AoC incorporating metamaterial and SIW technologies, (**a**) top view, and (**b**) side view.

The proposed SIW structure reduces substrate loss, radiation leakage, and adverse effects of surface wave propagation. This is achieved by carefully choosing the diameter and spacing of the metallic vias [16]. The subwavelength circular slots transform the array into a metasurface that has an effect of amplifying the effective aperture area of the antenna, the consequence of which is an enhancement in the radiation gain and efficiency of the antenna. In addition, the slots also improve the impedance match and bandwidth of the antenna.

The optimized structural parameters of the proposed AoC are given in Table 1. Optimization was done using CST Microwave Studio, which is a 3D full-wave electromagnetic simulation tool. The optimization involved parameterizing the antenna structure to achieve the target goal of $|S_{11}| \leq -10$ dB across 450–500 GHz. The optimizer used in CST Microwave Studio was the Covariance Matrix Adaptation Evolutionary Strategy (CMA-ES). This optimizer was used because it has a relatively fast convergence, and it uses the history of the previous iterations to improve the performance of the algorithm while avoiding local optimums. The AoC has a form factor of $0.8 \times 0.8 \times 0.13$ mm³. The effect of the circular slots and metallic vias on the performance parameters of the AoC are shown in Figures 2–4. It is evident that the metasurface and SIW significantly improve the antenna's impedance bandwidth to better than $S_{11} \leq -15$ dB, and the radiation gain and efficiency to over 0.45–0.5 THz. The average impedance match over 0.45–0.5 THz is approximately 30 dB, which an improvement of 15 dB without the slots and vias. The antenna has a fractional bandwidth of 10.52%. By incorporating the slots in the patches, the average radiation gain of the antenna increases to 6.5 dBi. This is an improvement of 2.7 dBi without the slots. The corresponding radiation efficiency increases to approximately 65%, which is an improvement of 12% without the slots. The average gain with the inclusion of the metallic vias is 6.5 dBi, which is an improvement of 4.4 dBi without the vias. The average efficiency with the metallic vias increases to about 65%, which is an improvement of 19% without the vias.

The E-plane and H-plane radiation patterns of the proposed AoC at 0.45 THz are shown in Figure 5. Clearly, the radiation patterns exhibit relatively high directivity in both planes. The half-power beam width in the *xy*-plane is 26° and that in the *xz*-plane is 17°. In addition, the side-lobe and back-lobe levels are all below -17.5 dBi in the *xz*-plane and below -22 dBi in the *xy*-plane.

Table 1. Optimized structural parameters of the AoC.

Parameter	Dimension	
Area occupied area by copper patches	400 μm ²	
Area occupied by aluminium patches	$600 \times 600 \ \mu m^2$	
Number of slots on each copper patch	7	
Thickness of the aluminium layer	10 µm	
Thickness of copper patches	10 µm	
Diameter of the slots	7 μm	
Gap between slots	26 µm	
Diameter of the metallic via	7 μm	
Gap between metallic vias	26 µm	
Width of gap between the patches	10 µm	
Thickness of the GaAs layer	100 μm	
Thickness of the ground-plane (GND) layer	10 µm	



Figure 2. Reflection-coefficient response of the proposed AoC (i) without metamaterial slots, (ii) without metallic vias, and (iii) with metamaterial slots and metallic vias.



Figure 3. Radiation gain as a function of the frequency of the proposed AoC (i) without metamaterial slots, (ii) without metallic vias, and (iii) with metamaterial slots and metallic vias.



Figure 4. Radiation efficiency as a function of the frequency of the proposed AoC (i) without metamaterial slots, (ii) without metallic vias, and (iii) with metamaterial slots and metallic vias.



Figure 5. Normalized radiation pattern of the proposed antenna on chip at 0.45 THz in the *xy*-plane and *xz*-plane.

3. Comparison with State-of-the-Art AoC

Table 2 compares the salient features of the proposed on-chip antenna with AoC reported in the literature. The maximum gain of the proposed antenna of 7.4 dBi is lower than [17,18] but it is comparable to references [11,19,20]. Additionally, it has a maximum

efficiency of 70%, which is lower than [17,19,20] but it is comparable to [11]. However, compared with the cited work in Table 2 the proposed antenna operates over a much higher frequency (between 450 and 500 GHz). Moreover, other than the antenna in [21] that operates over a much lower frequency range (50–70 GHz), the proposed antenna is much less thick with respect to the operating wavelength than other on-chip antennas reported to date. This is attributed to combining metasurface and SIW technologies in the implementation of the on-chip antenna. The thinner antenna structure is important to prevent the generation of surface or substrate modes that can adversely affect the antenna's performance, especially at THz frequencies [22].

Ref.	Antenna Design	Fractional Bandwidth (%) (Freq. Range (GHz))	Gain (dBi)	Eff. (%)	Dimensions (Physical and Electrical)
[11]	Patch fed higher order mode DRA	7.3 [330–355]	Max. 7.9	Max. 74	$0.2 \times 0.5 \text{ mm}^2$ $0.222\lambda_0 \times 0.555\lambda_0$ @330 GHz
[17]	On-chip 3D using Yagi-like concept	11.8 [320–360]	Max. 10	Max. 80	$\begin{array}{c} 0.7\times0.7\times0.43~\textrm{mm}^3\\ 0.75\lambda_0\times0.75\lambda_0\times0.46\lambda_0~\textrm{@320~GHz} \end{array}$
[18]	Dipole array antenna	10.7 [130.3–145]	Max. 20.5	Max. 59.2	$\begin{array}{c} 32 \times 20 \times 0.818 \ mm^{3} \\ 13.91 \lambda_{0} \times 8.69 \ \times \ 0.355 \lambda_{0} \ @130.3 \ GHz \end{array}$
[19]	Loop antenna	6 [65–69]	Max. 8	Max. 96.7	$0.7 imes 1.25 \ { m mm}^2 \ 0.151 \lambda_0 imes 0.271 \lambda_0$ @65 GHz
[20]	Half-mode cavity fed DRA	11.3 [125–140]	Max. 7.5	Max. 46	$0.8 \times 0.9 \times 1.3 \text{ mm}^3$ $0.333\lambda_0 \times 0.375 \times 0.541\lambda_0$ @125 GHz
[21]	Differential-fed	33.3 [50–70]	Max. –3.2	-	$\begin{array}{c} 1.5\times1.5\times0.3~\text{mm}^3\\ 0.25\lambda_0\times0.25\lambda_0\times0.05\lambda_0~\text{@50~GHz} \end{array}$
[23]	Bowtie-slot	15.4 [90–105]	Max1.78	-	$0.71 imes 0.31 imes 0.65 \text{ mm}^3$ $0.213\lambda_0 imes 0.093\lambda_0 imes 0.195\lambda_0$ @90 GHz
[24]	Ring-shaped monopole	33.3 [50–70]	Max. 0.02	Max. 35	-
[25]	Circular open-loop	16.1 [57–67]	Max4.4	-	$\begin{array}{c} 1.8\times1.8\times0.3~\textrm{mm}^3\\ 0.342\lambda_0\times0.342\lambda_0\times0.057\lambda_0~\textrm{@57~GHz} \end{array}$
[26]	AMC embedded slot antenna	126 [15–66]	Max. 2	-	$1.44 imes 1.1 imes 2 \text{ mm}^3$ $0.072\lambda_0 imes 0.055\lambda_0$ @15 GHz
[27]	Monopole	43.5 [45–70]	Max. 4.96	-	$\begin{array}{c} 1.953 \times 1.93 \times 0.25 \ \text{mm}^3 \\ 0.293 \lambda_0 \times 0.289 \lambda_0 \times 0.037 \lambda_0 \ \text{@45 GHz} \end{array}$
[28]	Dipole-antenna	7.1 [95–102]	Max. 4.8	-	-
[29]	Tab monopole	50 [45–75]	Max. 0.1	Max. 42	$\frac{1.5 \times 1 \text{ mm}^2}{1.5 \times 1 \text{ mm}^2 0.225 \lambda_0 \times 0.150 \lambda_0} \text{ @45 GHz}$
[30]	Slot fed stacked DRA	7.7 [125–135]	Max. 4.7	Max. 43	$\begin{array}{c} 0.9\times 0.8\times 1.5\ \text{mm}^3 \\ 0.375\lambda_0\times 0.333\ \times\ 0.625\lambda_0\ @125\ \text{GHz} \end{array}$
[31]	DRA	15.4 [120–140]	Max. 2.7	Max. 43	$\begin{array}{c} 0.9 \times 0.8 \times 0.6 \ \text{mm}^3 \\ 0.36 \lambda_0 \times 0.32 \ \times \ 0.24 \lambda_0 \ \text{@120 GHz} \end{array}$
[32]	Patch array antenna	11.6 [259–291]	Max. 5.2	-	$\begin{array}{c} 2.47 \times 1.53 \times 0.675 \ \textrm{mm}^3 \\ 2.14 \lambda_0 \times 1.33 \ \times \ 0.586 \lambda_0 \ \textrm{@259 GHz} \end{array}$
[33]	Octagonal shorted annular ring array antenna	5.4 [303–320]	Max. 4.1	Max. 38	$0.55 \times 0.5 \times 0.3 \text{ mm}^3$ $0.555\lambda_0 \ \times 0.505 \ \times \ 0.303\lambda_0 \ @303 \text{ GHz}$
This Work	Metasurface and SIW	10.5 [450–500]	Max. 7.4	Max. 70	$0.8 imes 0.8 imes 0.13 \text{ mm}^3$ $1.21\lambda_0 imes 1.21\lambda_0 imes 0.196\lambda_0$ @450 GHz

Table 2. Comparison of the proposed AoC with previous works reported in the literature.

4. Conclusions

The innovative design of an antenna is described for on-chip applications for terahertz applications. It is shown that by combining metasurface and SIW technologies in the antenna design, its impedance bandwidth, radiation gain, and efficiency performance are substantially enhanced. This is achieved without increasing the aperture area of the antenna. The antenna is constructed on a GaAs substrate and is composed of a 2×4 array of rectangular patches with a row of circular slots etched on it. It is excited through a microstrip coplanar waveguide feedline. Compared to AoC reported in the literature, the proposed antenna has a larger frequency bandwidth and operates at a much higher frequency with comparable gain and radiation efficiency.

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